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Document Version

Publisher's PDF, also known as Version of record

Publication date:
2009

[Link to publication in University of Groningen/UMCG research database](#)

Citation for published version (APA):

Vlooswijk, A. H. G. (2009). *Structure and domain formation in ferroelectric thin films*. [Thesis fully internal (DIV), University of Groningen]. [s.n.].

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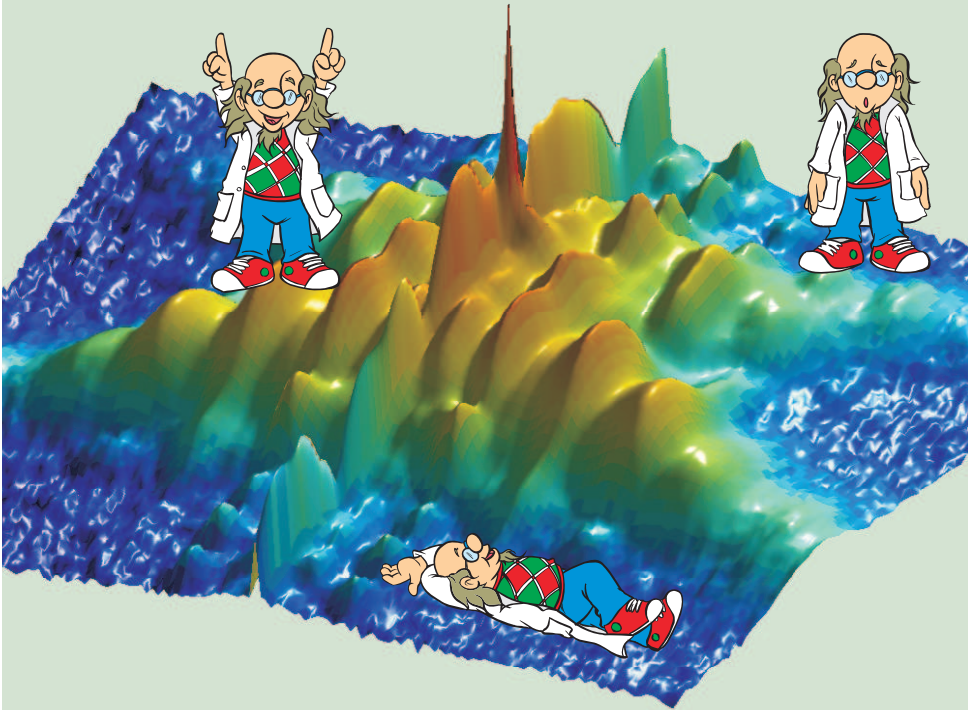
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Structure and domain formation in ferroelectric thin films



Ard H.G. Vlooswijk

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This research has been performed in the Solid State Chemistry group of the Zernike Institute for Advanced Materials at the University of Groningen, the Netherlands. It was part of the research program of the Nederlandse Organisatie voor Wetenschappelijk Onderzoek (NWO).



University of Groningen
**Zernike Institute
for Advanced Materials**



Nederlandse Organisatie voor Wetenschappelijk Onderzoek

Zernike Institute PhD thesis series 2009-09
ISSN 1570-1530

Cover: (front) Solid state chemists in the “up” and “down” state and “relaxed”, while being lost in the reciprocal space around the (001) Bragg reflection of a SrRuO₃/ 16nm PbTiO₃/ SrRuO₃ capacitor on a DyScO₃ substrate.

(back) Real space atomic force micrograph of a thin film of 30nm PbTiO₃ on 30nm SrRuO₃ on DyScO₃ with crystallographic twins represented by vertical lines with different thicknesses. The chemists at the top form a periodic “up” and “down” pattern, while those at the bottom represent the periodic pattern of the “relaxed” thin film with their “long axis” alternately horizontal (in-plane) and vertical (out-of-plane). The solid state chemists are drawn by Dave Elderenbosch, the measurements have been performed by Ard Vlooswijk at (front) beamline W1, DESY, Hamburg and (back) the Zernike Institute for Advanced Materials, Groningen.

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RIJKSUNIVERSITEIT GRONINGEN

Structure and domain formation
in ferroelectric thin films

Proefschrift

ter verkrijging van het doctoraat in de
Wiskunde en Natuurwetenschappen
aan de Rijksuniversiteit Groningen
op gezag van de
Rector Magnificus, dr. F. Zwarts,
in het openbaar te verdedigen op
vrijdag 12 juni 2009
om 14.45 uur

door

Adrianus Henricus Gerardus Vlooswijk

geboren op 23 oktober 1979
te Utrecht

Promotores: Prof. dr. B. Noheda
Prof. dr. T. T. M. Palstra

Beoordelingscommissie: Prof. dr. ing. D. H. A. Blank
Prof. dr. B. Dam
Prof. dr. J. Th. M. De Hosson

ISBN:

in gedrukte vorm : 978-90-367-3836-1

digitaal (.pdf) : 978-90-367-3846-0